<u>Claims</u>

1	1. In combination:
2	a fluoropolymer matrix having particles distributed
3	therein; and
4	a thermosetting resin.
1	2. The combination of claim 1, further comprising a metal
2	layer contacting the fluoropolymer matrix.
j.	3. The combination of claim 1, wherein the fluoropolymer
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= 1	4. The combination of claim 1, wherein the fluoropolymer
	matrix is polytetrafluoroethylene.
1	5. The combination of claim 1, wherein the thermosetting
2	resin includes a contrasting dye and inorganic fillers.
1	6. The combination of claim 1, wherein the thermosetting
2	resin is selected from the group consisting of
3	cycloaliphatic type epoxies, digycidyl ethers of bispheno
4	A, cresol novolaks, phenolic epoxies, bismaleimides,

- 5 polyimides, bismaleimides-triazine epoxies, and cyanate
- 6 ester-epoxy mixtures.
- 7. The combination of claim 1, wherein the thermosetting
- 2 resin is impregnated into the fluoropolymer matrix.
- 8. The combination of claim 1, wherein the particles in the
- 2 fluoropolymer matrix are inorganic.
 - 9. The combination of claim 1, wherein the particles comprise about 15 to about 95 percent of a volume of the fluoropolymer matrix.
 - 10. The combination of claim 1, wherein the particles have a diameter of less that 10 $\mu m\,.$
- 1 11. The combination of claim 1, wherein the thermosetting
 - 2 resin includes inorganic particles.

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- 1 12. A device, comprising:
- 2 a conductive layer;
- a polytetrafluoroethylene matrix, containing particles
- 4 therein, overlaying the conductive layer; and
- a thermosetting resin, for bonding the conductive layer
- to the polytetrafluoroethylene matrix.
- 1 13. The device of claim 12, wherein the
- 2 polytetrafluoroethylene matrix is nonfibrillated.
 - 14. The device of claim 12, wherein the thermosetting resin is impregnated into the polytetrafluoroethylene matrix.
 - 15. The device of claim 12 wherein the thermosetting resin is coated onto the conductive layer.
 - 16. The device of claim 12 wherein the thermosetting resin is coated onto the polytetrafluoroethylene matrix.
- 1 17. The device of claim 12, wherein the conductive layer is
- 2 copper.
- 1 18. The device of claim 12, wherein the thermosetting resin

- 2 is provided in a sheet positionable between the conductive
- 3 layer and the polytetrafluoroethylene matrix.
- 1 19. The device of claim 12, wherein the particles in the
- 2 polytetrafluoroethylene matrix are inorganic particles.
- 1 20. The device of claim 12, wherein the thermosetting resin
- 2 includes inorganic particles.
 - 21. The device of claim 12, wherein the device is a printed circuit board.
 - 22. The device of claim 12, wherein the device is a chip carrier.

- 23. A method for forming a device, comprising the following 1 2 steps:
- 3 providing a fluoropolymer matrix having particles 4 therein;
- 5 providing a thermosetting resin; and
- 6 laminating the fluoropolymer matrix to a conductor 7 using the thermosetting resin.
- 24. The method of claim 23, wherein the fluoropolymer matrix 1 CAN SERVED THE COLUMN C is nonfibrillated polytetrafluoroethylene.
 - 25. The method of claim 23, wherein the particles are inorganic particles.
 - 26. The method of claim 23, wherein the thermosetting resin is impregnated into the fluoropolymer matrix.
- 27. The method of claim 23, wherein the thermosetting resin 1 2 is coated onto the conductor.
- 1 28. The method of claim 23, wherein the thermosetting resin 2 is coated onto the fluoropolymer matrix.

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- 1 29. The method of claim 23, wherein the conductor is copper.
- 1 30. The method of claim 23, wherein the thermosetting resin
- is provided in a sheet that is positioned between the
- 3 fluoropolymer matrix and the conductor.
- 1 31. The method of claim 23, wherein the thermosetting resin
- 2 includes a contrasting dye.
 - 32. The method of claim 23, wherein the device is a printed circuit board.
 - 33. The device of claim 23, wherein the device is a chip carrier.

- 34. A method for forming a device, comprising the following steps:
- providing a fluoropolymer matrix having particles
 therein;
- 5 coating the fluoropolymer matrix with a thermosetting 6 resin; and
- 1 laminating the coated fluoropolymer matrix to a conductor.
 - 35. The method of claim 34, wherein the thermosetting resin includes solvent.
 - 36. The method of claim 35, further comprising the step of heating the coated fluoropolymer matrix to remove the solvent from the thermosetting resin, prior to the laminating step.
- 1 37. The method of claim 34, further comprising the step of
- 2 subjecting the fluoropolymer matrix to a plasma process,
- 3 prior to the coating step.

- 1 38. The method of claim 34, wherein the fluoropolymer matrix
- is a nonfibrillated polytetrafluoroethylene.
- 1 39. The method of claim 34, wherein the thermosetting resin
- 2 contains about 30-75 percent solids.
- 1 40. The method of claim 34, wherein the laminating step
- 2 comprises applying heat and pressure.
 - 41. The method of claim 40, wherein the heat is applied to about $120-250^{\circ}$ C during the laminating step.
 - 42. The method of claim 40, wherein the pressure is applied to about 100-700 PSI during the laminating step.
 - 43. The method of claim 34, wherein the fluoropolymer matrix is impregnated with the thermosetting resin, prior to the providing step.
- 1 44. The method of claim 34, wherein the conductor is copper.

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Τ	45. The method of claim 34, further comprising the steps of:
2	coating the conductor with the thermosetting resin,
3	prior to the laminating step; and
4	heating the coated conductor to remove the solvent from
5	the thermosetting resin.